

# 6MBP150RA120

## IGBT-IPM R series

1200V / 150A 6 in one-package

### Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



### Maximum ratings and characteristics

- Absolute maximum ratings(at Tc=25°C unless otherwise specified)

Item	Symbol	Rating		Unit
		Min.	Max.	
DC bus voltage	V <sub>DC</sub>	0	900	V
DC bus voltage (surge)	V <sub>DC(surge)</sub>	0	1000	V
DC bus voltage (short operating)	V <sub>SC</sub>	200	800	V
Collector-Emitter voltage	V <sub>CEs</sub>	0	1200	V
INV Collector current	DC	I <sub>c</sub>	- 150	A
	1ms	I <sub>CP</sub>	- 300	A
	DC	-I <sub>c</sub>	- 150	A
Collector power dissipation	One transistor	P <sub>c</sub>	- 1040	W
Junction temperature	T <sub>j</sub>	-	150	°C
Input voltage of power supply for Pre-Driver	V <sub>CC</sub> *1	0	20	V
Input signal voltage	V <sub>in</sub> *2	0	V <sub>Z</sub>	V
Input signal current	I <sub>in</sub>	-	1	mA
Alarm signal voltage	V <sub>ALM</sub> *3	0	V <sub>CC</sub>	V
Alarm signal current	I <sub>ALM</sub> *4	-	15	mA
Storage temperature	T <sub>stg</sub>	-40	125	°C
Operating case temperature	T <sub>op</sub>	-20	100	°C
Isolating voltage (Case-Terminal)	V <sub>iso</sub> *5	-	AC2.5	kV
Screw torque	Mounting (M5)	-	3.5 *6	N·m
	Terminal (M5)	-	3.5 *6	N·m

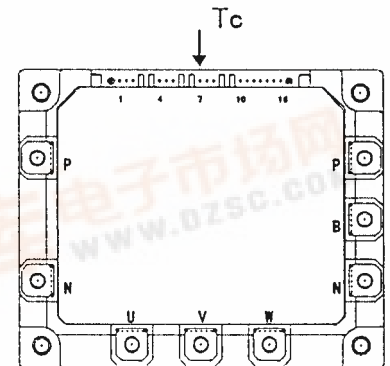


Fig.1 Measurement of case temperature

\*1 Apply V<sub>CC</sub> between terminal No. 3 and 1, 6 and 4, 9 and 7, 11 and 10.  
 \*2 Apply V<sub>in</sub> between terminal No. 2 and 1, 5 and 4, 8 and 7, 13,14,15 and 10.  
 \*3 Apply V<sub>ALM</sub> between terminal No. 16 and 10.  
 \*4 Apply I<sub>ALM</sub> to terminal No. 16.  
 \*5 50Hz/60Hz sine wave 1 minute.  
 \*6 Recommendable Value : 2.5 to 3.0 N·m

### Electrical characteristics of power circuit (at Tc=Tj=25°C, V<sub>CC</sub>=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
INV Collector current at off signal input	I <sub>CEs</sub>	V <sub>CE</sub> =1200V input terminal open	-	-	1.0	mA
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>c</sub> =150A	-	-	2.6	V
Forward voltage of FWD	V <sub>F</sub>	-I <sub>c</sub> =150A	-	-	3.0	V



● Electrical characteristics of control circuit(at Tc=Tj=25°C, Vcc=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Power supply current of P-line side Pre-driver(one unit)	Iccp	fsw=0 to 15kHz Tc=-20 to 100°C *7	3	-	18	mA
Power supply current of N-line side three Pre-driver	Iccn	fsw=0 to 15kHz Tc=-20 to 100°C *7	10	-	65	mA
Input signal threshold voltage (on/off)	Vin(th)	ON	1.00	1.35	1.70	V
		OFF	1.70	2.05	2.40	V
Input zener voltage	Vz	Rin=20k ohm	-	8.0	-	V
Over heating protection temperature level	TcOH	VDC=0V, Ic=0A, Case temperature, Fig.1	110	-	125	°C
Hysteresis	TcH		-	20	-	°C
IGBT chips over heating protection temperature level	TjOH	surface of IGBT chips	150	-	-	°C
Hysteresis	TjH		-	20	-	°C
Collector current protection level	INV	Ioc	Tj=125°C	225	-	A
Over current protection delay time	tDOC	Tj=25°C Fig.2	-	10	-	µs
Under voltage protection level	VUV		11.0	-	12.5	V
Hysteresis	VH		0.2	-	-	V
Alarm signal hold time	tALM		1.5	2	-	ms
SC protection delay time	tSC	Tj=25°C Fig.3	-	-	12	µs
Limiting resistor for alarm	RALM		1425	1500	1575	ohm

\*7 Switching frequency of IPM

● Dynamic characteristics(at Tc=Tj=125°C, Vcc=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Switching time (IGBT)	ton	Ic=150A, VDC=600V	0.3	-	-	µs
	toff		-	-	3.6	µs
Switching time (FWD)	trr	IF=150A, VDC=600V	-	-	0.4	µs

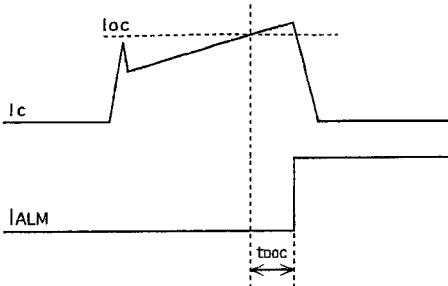


Fig.2 Definition of OC delay time

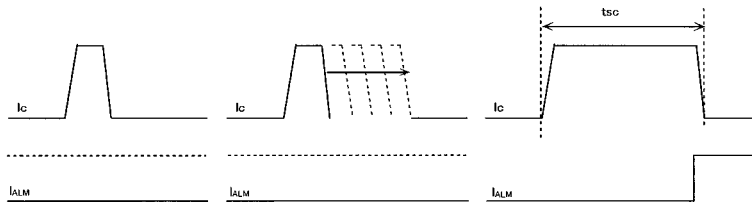


Fig.3 Definition of tsc

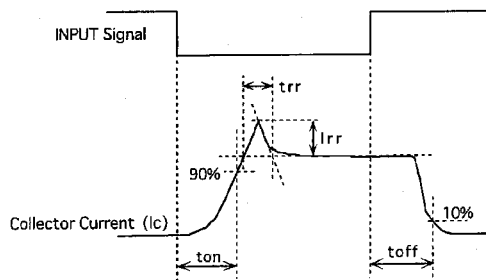


Fig.4 Definition of switching time

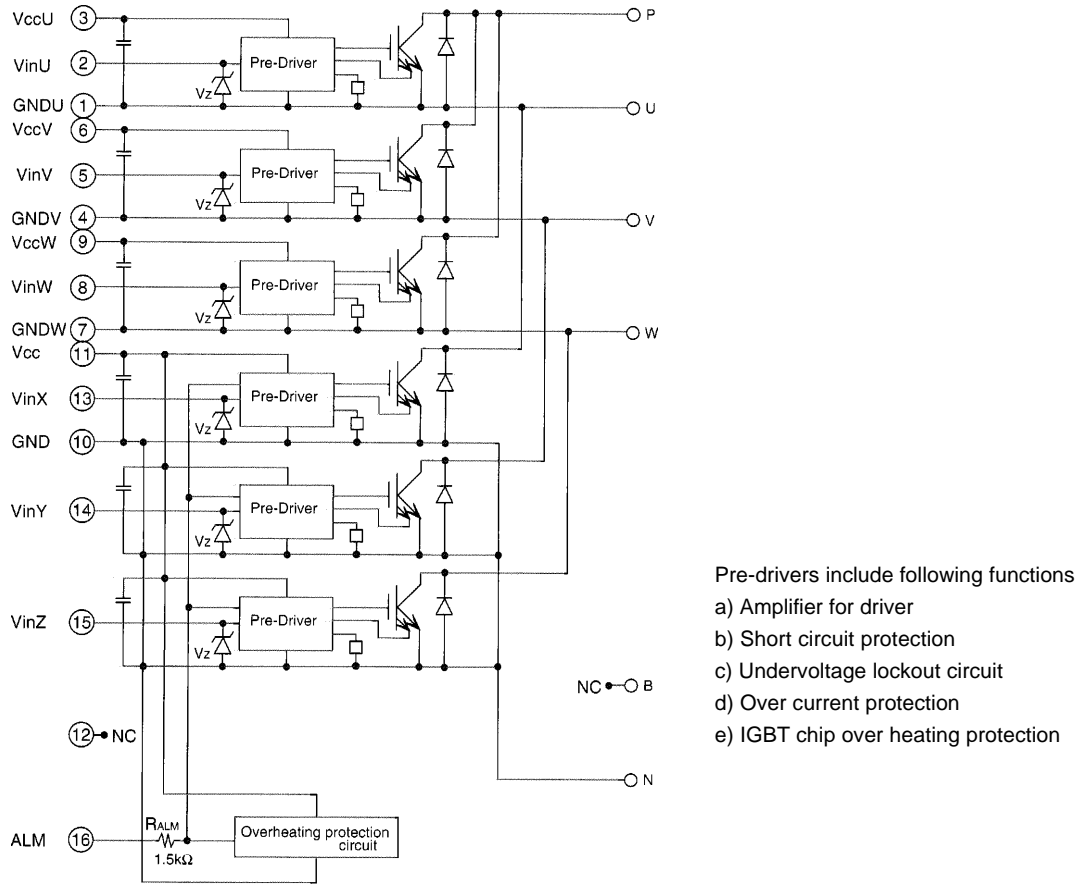
● Thermal characteristics(Tc=25°C)

Item	Symbol	Typ.	Max.	Unit		
Junction to Case thermal resistance	INV	IGBT	Rth(j-c)	-	0.12	°C/W
		FWD	Rth(j-c)	-	0.29	°C/W
Case to fin thermal resistance with compound	Rth(c-f)	0.05	-	°C/W		

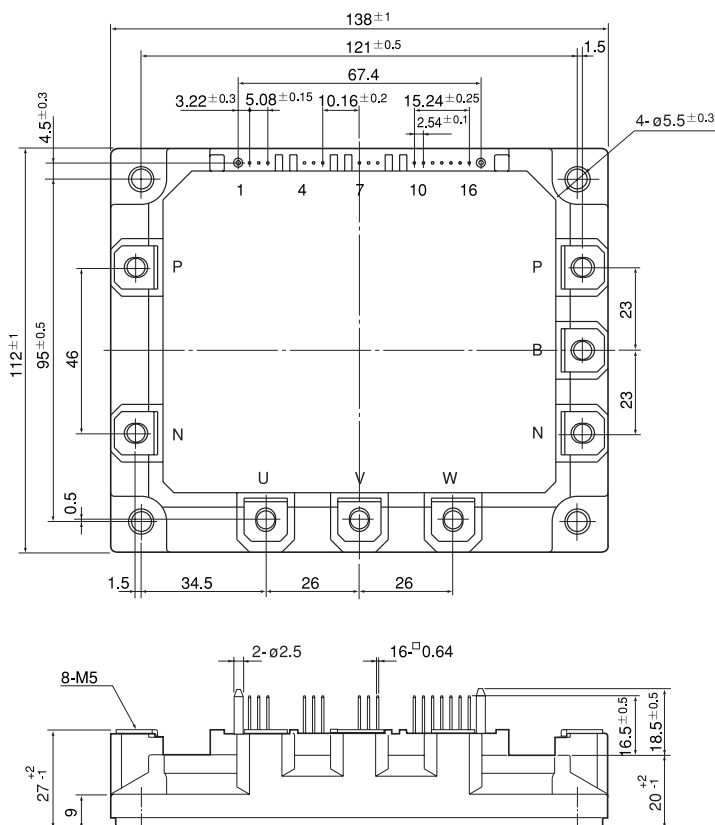
● Recommendable value

Item	Symbol	Min.	Typ.	Max.	Unit	
DC bus voltage	VDC	200	-	800	V	
Operating power supply voltage range of Pre-driver	Vcc	13.5	15	16.5	V	
Switching frequency of IPM	fsw	1	-	20	kHz	
Screw torque	Mounting (M5)	-	2.5	-	3.0	N·m
	Terminal (M5)	-	2.5	-	3.0	N·m

Block diagram



Outline drawings, mm

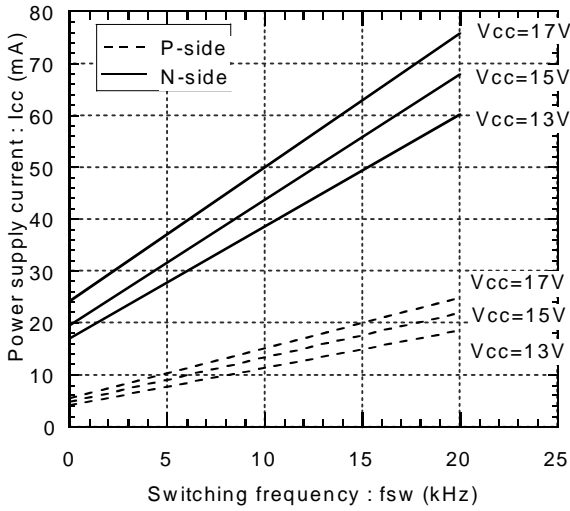


Mass : 920g

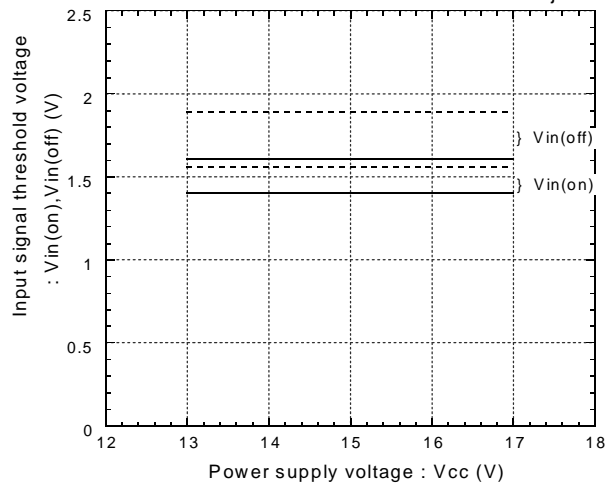
Characteristics (Representative)

Control Circuit

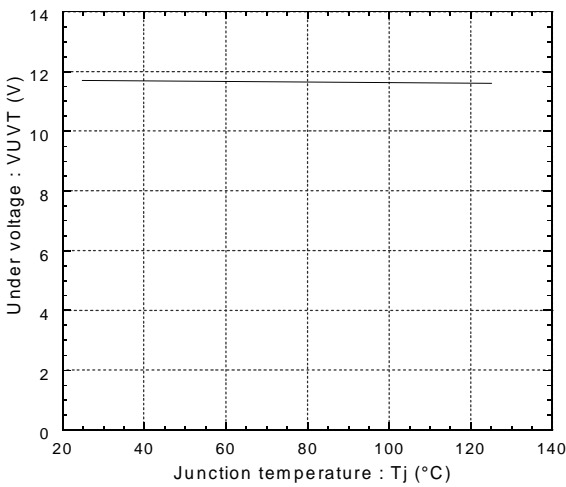
Power supply current vs. Switching frequency  
Tj=100°C



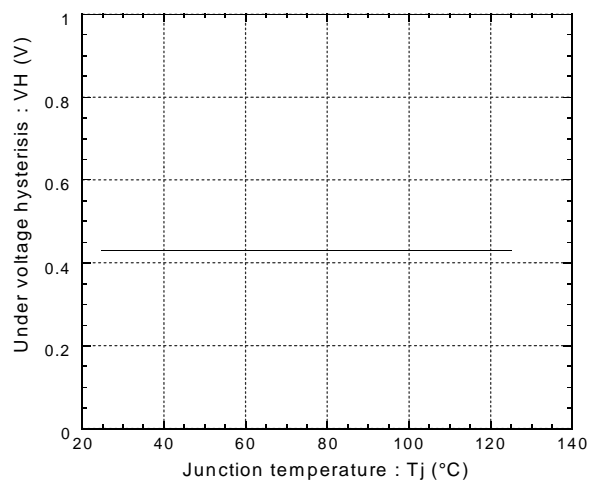
Input signal threshold voltage vs. Power supply voltage  
Tj=25°C (solid line), Tj=125°C (dashed line)



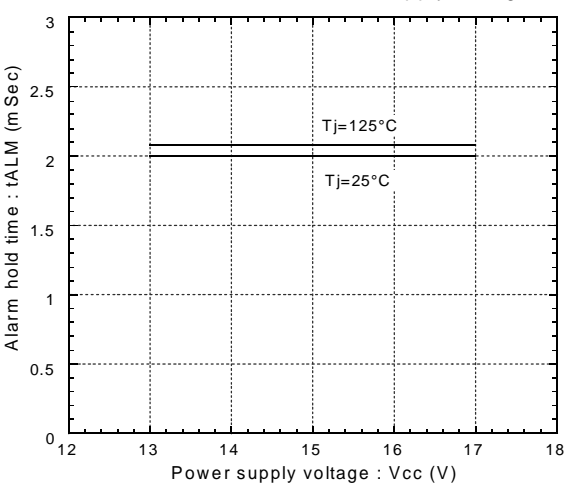
Under voltage vs. Junction temperature



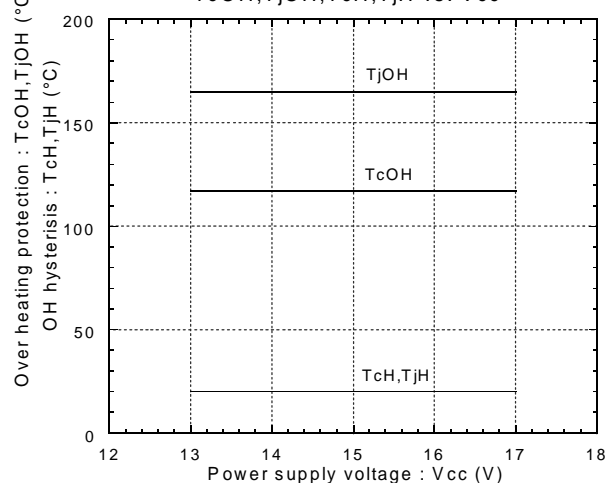
Under voltage hysteresis vs. Junction temperature



Alarm hold time vs. Power supply voltage

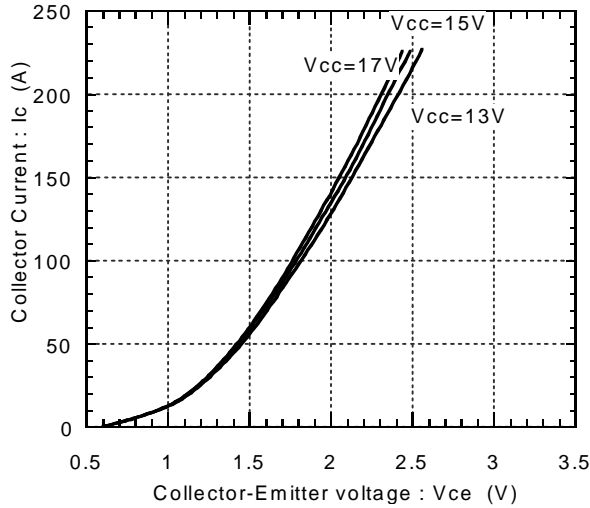


Over heating characteristics  
TcOH, TjOH, TcH, TjH vs. Vcc

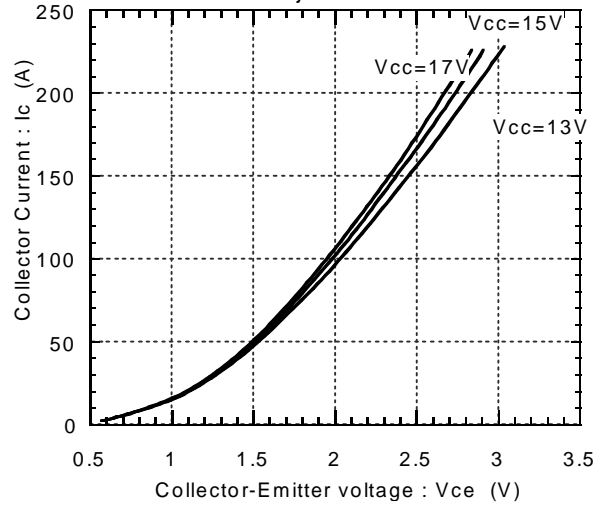


● Inverter

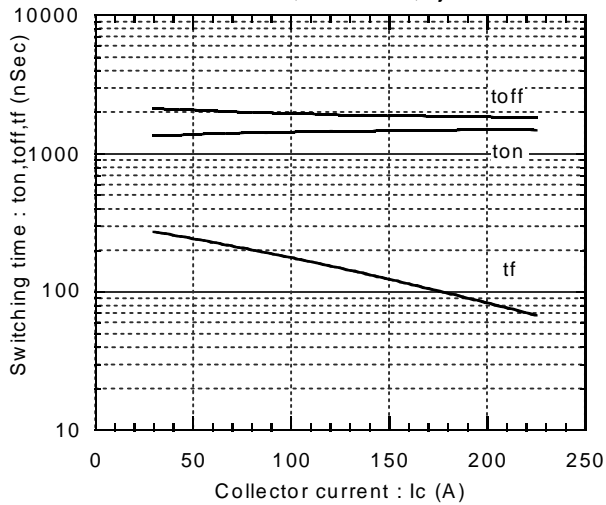
Collector current vs. Collector-Emittter voltage  
T<sub>j</sub>=25°C



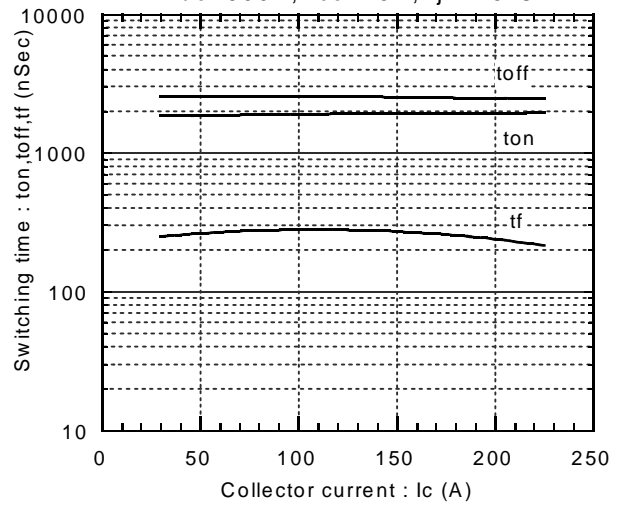
Collector current vs. Collector-Emittter voltage  
T<sub>j</sub>=125°C



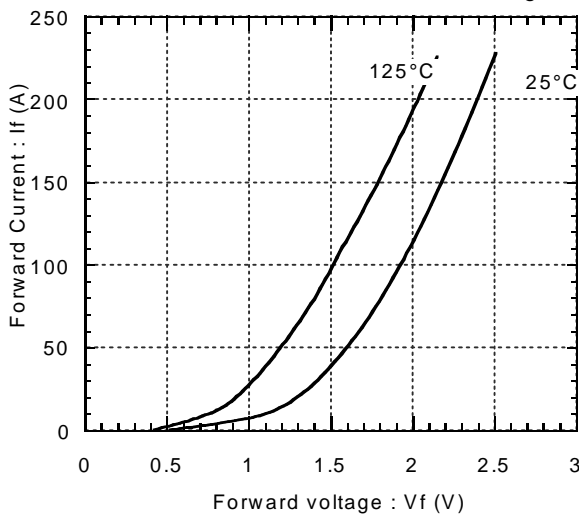
Switching time vs. Collector current  
E<sub>dc</sub>=600V, V<sub>cc</sub>=15V, T<sub>j</sub>=25°C



Switching time vs. Collector current  
E<sub>dc</sub>=600V, V<sub>cc</sub>=15V, T<sub>j</sub>=125°C



Forward current vs. Forward voltage



Reverse recovery characteristics  
trr, Irr vs. IF

